

**Features:**

- Isolated mounting base 3000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving
- Typical Applications**
- Various rectifiers
- DC supply for PWM inverter

V _{RRM}	Type & Outline		
	MDx600-08-416F3	MDx600-10-416F3	MDx600-12-416F3
800V			
1000V			
1200V			
1400V			
1600V			
1800V			
1800V	MDx600-16-416F3	MDx600-18-416F3	MD600-18-416F3G

MDx stands for any type of **MDC**, **MDA**, **MDK**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _c =100°C	150			600	A
I _{F(RMS)}	RMS forward current					942	A
I _{RRM}	Repetitive peak current	at V _{RRM}	150			45	mA
I _{FSM}	Surge forward current	V _R =60%V _{RRM} , t=10ms half sine,	150			19.0	kA
I ² t	I ² t for fusing coordination					1805	10 ³ A ² s
V _{FO}	Threshold voltage		150			0.75	V
r _F	Forward slope resistance					0.28	mΩ
V _{FM}	Peak forward voltage	I _{FM} =1800A	25			1.50	V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled per chip				0.065	°C/W
R _{th(c-h)}	Thermal resistance case to heatsink	Single side cooled per chip				0.024	°C/W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I _{iso} :1mA(MAX)		3000			V
F _m	Terminal connection torque(M10)			10		12	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T _{vj}	Junction temperature			-40		150	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				1490		g
Outline			416F3				

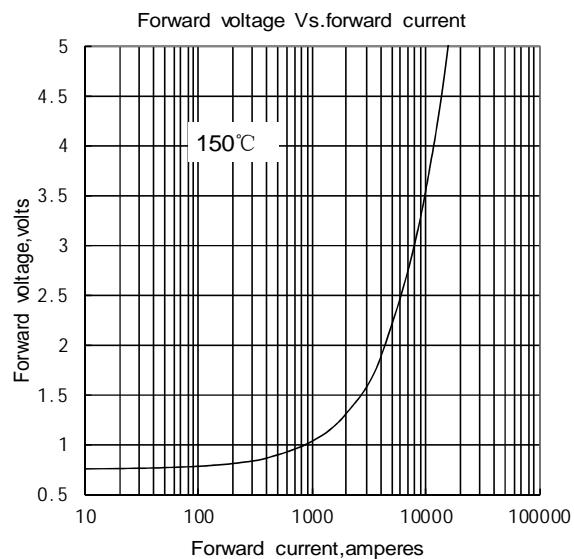


Fig.1

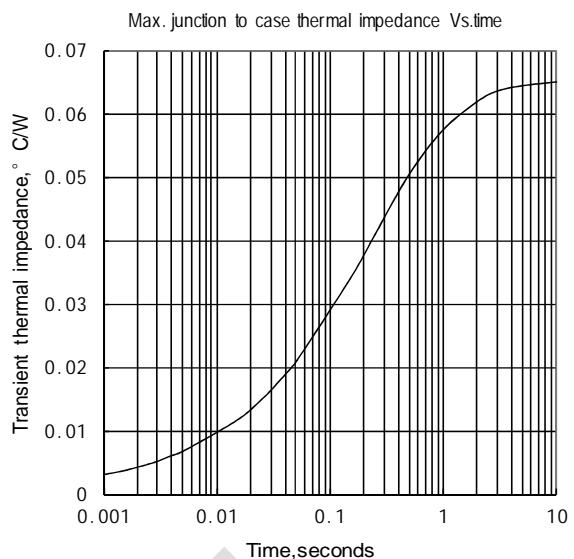


Fig.2

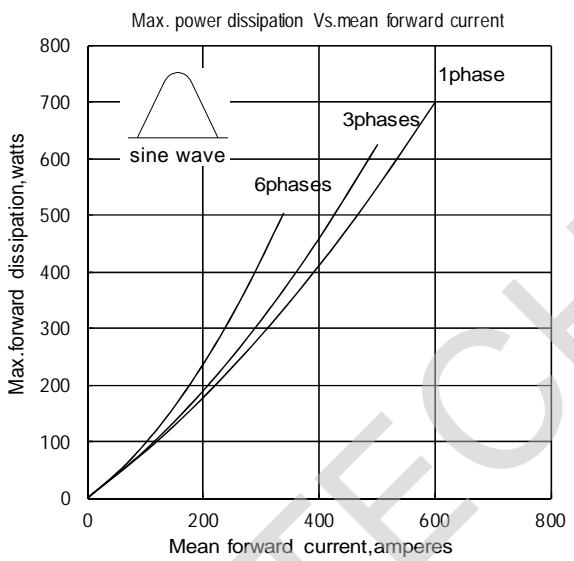


Fig.3

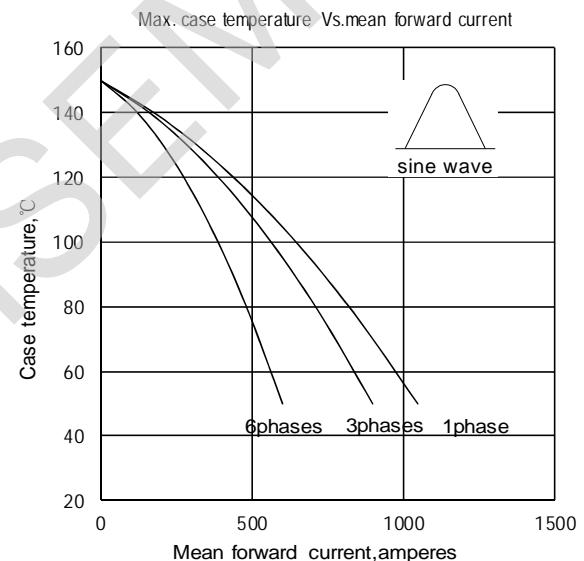


Fig.4

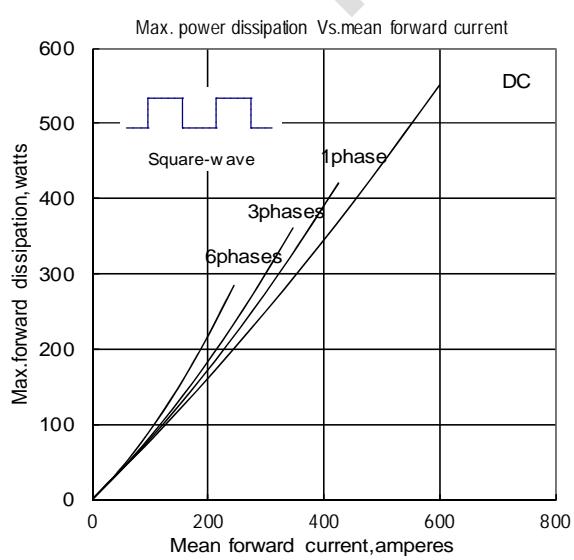


Fig.5

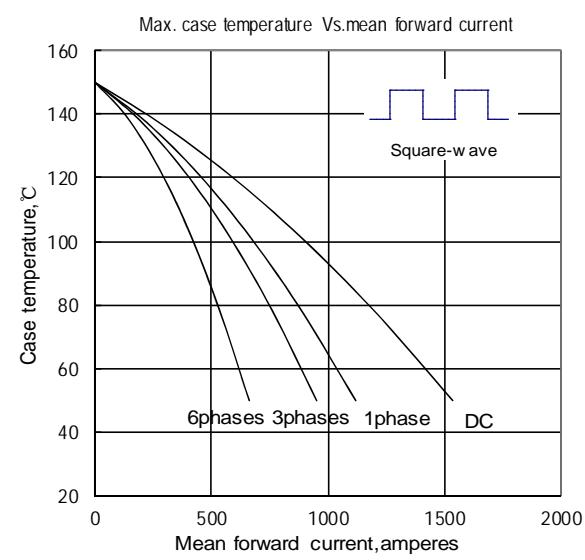


Fig.6

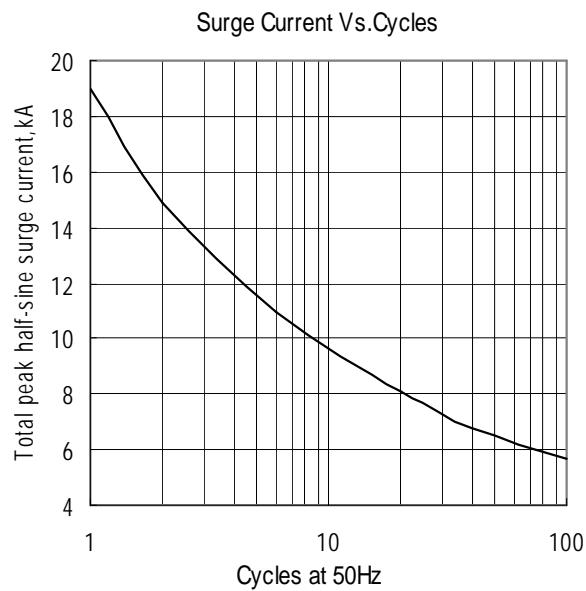


Fig.7

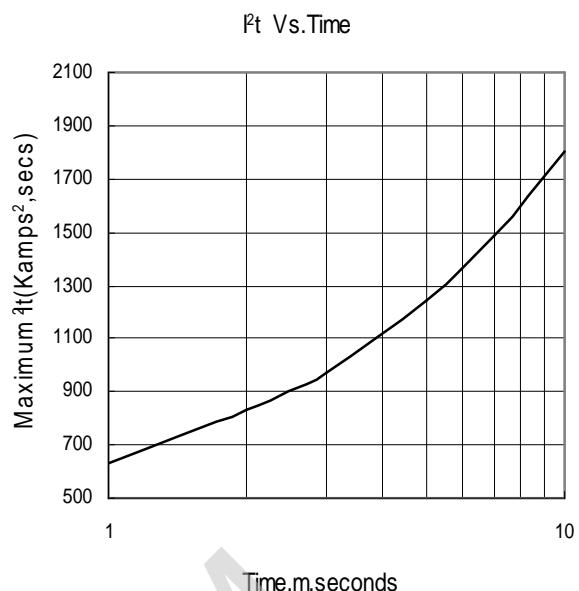
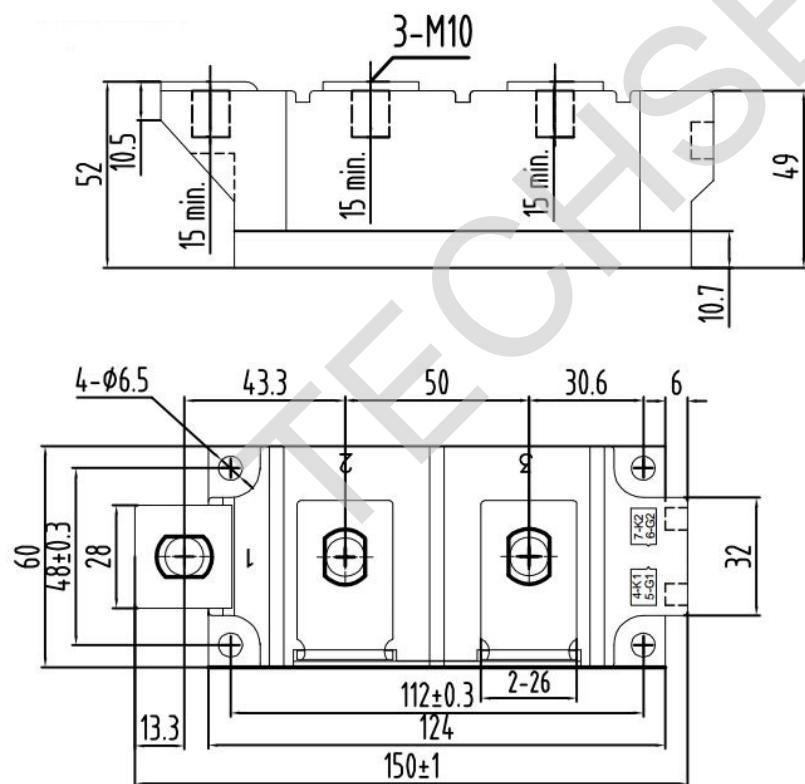


Fig.8

Outline:Unmarked dimensional tolerance: $\pm 0.5\text{mm}$ 